## SiC Schottky Diode Full Bridge Power Module

**Features** 

Preliminary

- Zero reverse recovery
- Zero forward recovery
- Temperature-independent switching behavior
- Positive temperature coefficient on VF
- Very low stray inductance
- High level of integration

## **Benefits**

- Outstanding performance at high-frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

## **Applications**

- Switch mode power supplies rectifier
- Induction heating
- Welding equipment
- High-speed rectifiers

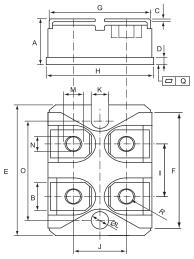
# **Maximum Ratings**

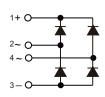
Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI4×25-170L1B	1700V	1700V

Maximum Rating	Symbol	Conditions	Value	Unit	
		Tc=25°C	60		
Continuous forward current (per diode)	I <sub>F</sub>	Tc=125°C	30	Α	
,		Tc=135°C	25		
		Tc=25°C, tp=8.3ms half sine wave	200		
Non-repetitive peak forward surge current (per diode)	I <sub>FSM</sub>	Tc=150°C, tp=8.3ms half sine wave	125	Α	
		Tc=25°C, tp=10µs pulse	800		
Repetitive peak forward surge current (per diode)		Tc=25°C, tp=10ms half sine wave, D=0.1	160	A	
	I <sub>FRM</sub>	Tc=125°C, tp=10ms half sine wave, D=0.1	88		
DC blocking voltage	$V_R$	Tj=25°C	1700	V	
Repetitive peak reverse voltage	$V_{RRM}$	Tj=25°C	1700	٧	
Isolation voltage	V <sub>iso</sub>	50/60Hz, RMS I <sub>ISOL</sub> ≤ 1mA	2500	٧	
Operating junction and storage temperature	$T_j$		175	°C	
	$T_{stg}$		-55 to 175	C	
Mounting torque		To heatsink	1.5	Nm	
mounting torque		To terminal	1.3	INIII	

VRRM=1,700V IF=25A@Tc=135°C







DIMENSIONS						
	INCHES			I		
	INCH	ies	М	Л		
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
E	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
I	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
M	0.181	0.197	4.60	5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					

#### Electrical Characteristics, at T<sub>i</sub>=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	$V_{DC}$		1,700	-	-	
Diode forward voltage	V <sub>F</sub>	I <sub>F</sub> =25A, T <sub>j</sub> =25 °C	-	1.6	1.8	V
		I <sub>F</sub> =25A, T <sub>j</sub> =175 °C	-	2.4	2.9	
	I_	V <sub>R</sub> =1,700V, T <sub>j</sub> =25 °C	-	20	50	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1,700V, T <sub>j</sub> =175 °C	-	50	200	μΑ

#### AC Characteristics (per diode)

Static Characteristics	Completel	Conditions min.	Values			
	Symbol		min.	typ.	max.	Unit
Total capacitive charge	Q <sub>rr</sub>	V <sub>R</sub> =800V I <sub>F</sub> =25A, T <sub>j</sub> =25 °C	-	58	-	nC
Total capacitance		V <sub>R</sub> =0V, f=1 MHz T <sub>j</sub> =25 °C	-	1,302	-	pF
	С	V <sub>R</sub> =800V, f=1 MHz T <sub>j</sub> =25 °C	-	114.5	-	
		V <sub>R</sub> =1000V, f=1 MHz T <sub>j</sub> =25 °C	-	113.9	-	

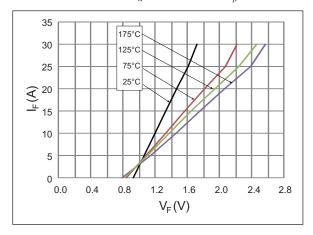
#### Thermal Characteristics (per diode)

Static Characteristics	Comple ed	Values	Unit	
Static Characteristics	Symbol	typ.		
Thermal resistance from junction to case	$R_{ hetaJC}$	0.56	°C/W	

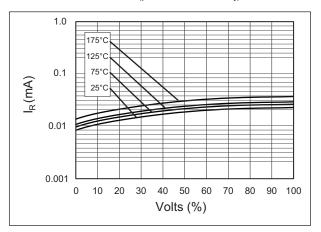
2021.09.27 Rev. 1.0

#### **Typical Performance**

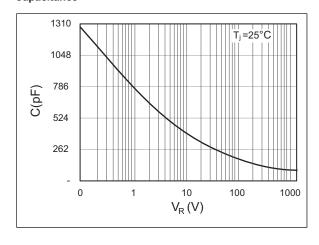
#### Forward Characteristics (parameterized on T<sub>i</sub>)



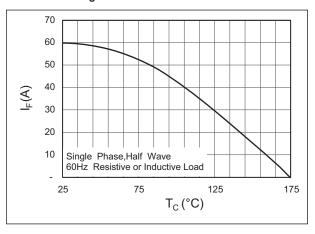
#### Reverse Characteristics (parameterized on Tj)



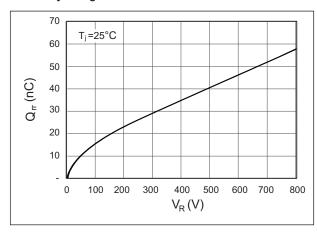
#### Capacitance



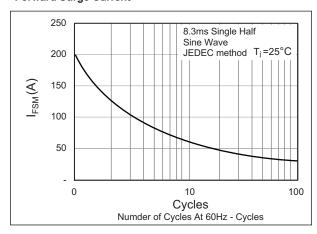
#### **Current Derating**



#### **Recovery Charge**



#### **Forward Surge Current**





### **Disclaimer**

DACO Semiconductor reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein.

DACO Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does DACO Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

Purchasers is responsible for its products and applications using DACO Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by DACO Semiconductor. "Typical" parameters which may be provided in DACO Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts.

DACO Semiconductor products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of DACO Semiconductor's product can reasonably be expected to result in personal injury, death or severe property or environmental damage. DACO Semiconductor accept no liability for inclusion and/or use of DACO Semiconductor's products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Purchasers buy or use DACO Semiconductor products for any such unintended or unauthorized application, Purchasers shall indemnify and hold DACO Semiconductor and its suppliers and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that DACO Semiconductor was negligent regarding the design or manufacture of the part.

No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of DACO Semiconductor Co., Ltd.

www.dacosemi.com.tw